Unit: mm

TOSHIBA Transistor Silicon NPN Epitaxial Type (PCT Process)

# 2SC2383

## Color TV Vertical Deflection Output Applications Color TV Class-B Sound Output Applications

- High breakdown voltage: VCEO = 160 V
- Large continuous collector current capability
- Recommended for vertical deflection output & sound output applications for line-operated TVs.
- Complementary to 2SA1013

### Absolute Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Rating	Unit
Collector-base voltage	$V_{CBO}$	160	V
Collector-emitter voltage	$V_{CEO}$	160	V
Emitter-base voltage	V <sub>EBO</sub>	6	V
Collector current	IC	1	Α
Base current	ΙΒ	0.5	Α
Collector power dissipation	PC	900	mW
Junction temperature	Tj	150	°C
Storage temperature range	T <sub>stg</sub>	-55 to 150	°C

1. EMITTER 2. COLLECTOR 3. BASE

JEDEC TO-92MOD

JEITA —

TOSHIBA 2-5J1A

Weight: 0.36 g (typ.)

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

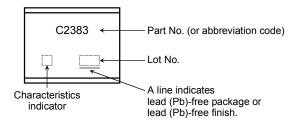


# Electrical Characteristics (Ta = 25°C)

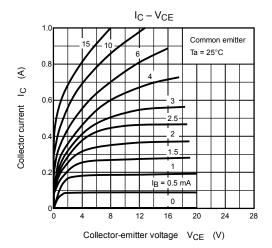
Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Collector cut-off current	I <sub>CBO</sub>	V <sub>CB</sub> = 150 V, I <sub>E</sub> = 0	_	_	1.0	μΑ
Emitter cut-off current	I <sub>EBO</sub>	V <sub>EB</sub> = 6 V, I <sub>C</sub> = 0	_	_	1.0	μA
Collector-emitter breakdown voltage	V (BR) CEO	I <sub>C</sub> = 10 mA, I <sub>B</sub> = 0	160	_	_	V
DC current gain	h <sub>FE</sub> (Note)	V <sub>CE</sub> = 5 V, I <sub>C</sub> = 200 mA	60	_	320	
Collector-emitter saturation voltage	V <sub>CE (sat)</sub>	I <sub>C</sub> = 500 mA, I <sub>B</sub> = 50 mA	_	_	1.5	V
Base-emitter voltage	V <sub>BE</sub>	V <sub>CE</sub> = 5 V, I <sub>C</sub> = 5 mA	0.45	_	0.75	V
Transition frequency	f <sub>T</sub>	V <sub>CE</sub> = 5 V, I <sub>C</sub> = 200 mA	20	100	_	MHz
Collector output capacitance	C <sub>ob</sub>	V <sub>CB</sub> = 10 V, I <sub>E</sub> = 0, f = 1 MHz	_	_	20	pF

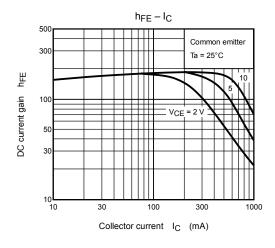
Note: hFE classification R: 60 to 120, O: 100 to 200, Y: 160 to 320

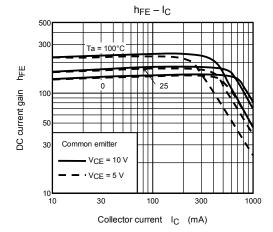
## Marking

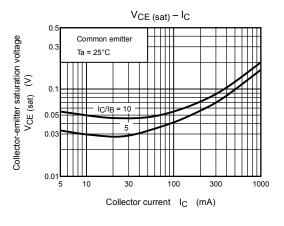


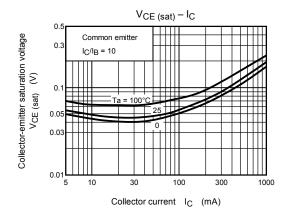
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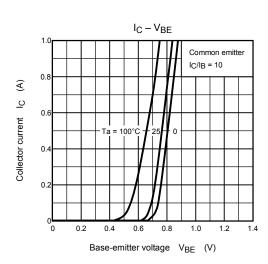


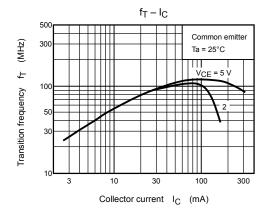


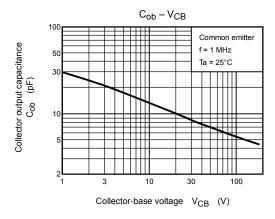


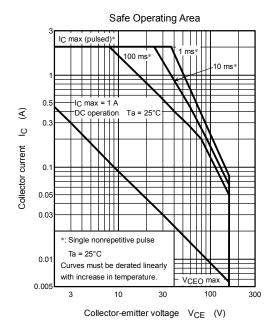












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